

单向硅整流桥堆

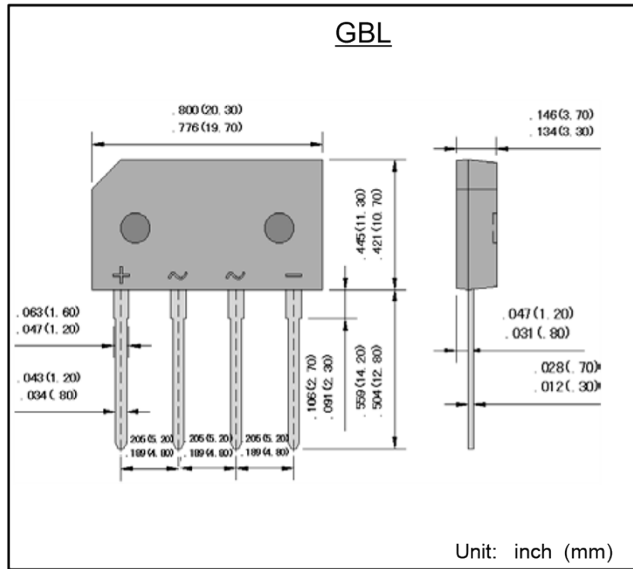
反向电压 50 ~ 800 V

正向电流 1.5 A

Single phase Silicon Bridge Rectifiers

Reverse Voltage 50 ~ 800 V

Forward Current 1.5 A



特征 Features

- 反向漏电流低 Low reverse leakage
- 正向浪涌承受能力强 High forward surge capability
- 高信赖性 High reliability
- 玻璃钝化芯片 Glass passivated chip
- 引线 and 管体皆符合RoHS标准
Lead and body according with RoHS standard
- 型号后缀“-F”标记无卤素产品
Green compound with suffix "-F" on Marking

机械数据 Mechanical Data

- 封装外形:GBL 塑封 Case:GBL Molded plastic
- 环氧树脂:UL易燃等级:94V-0
Epoxy: UL 94V-0 rate flame retardant
- 引脚:镀锡,无铅 Lead: Pure tin plated, lead free
- 安装位置:任意 Mounting Position: Any

最大值和特性 TA = 25°C 除非另有规定。

Maximum Ratings & Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

参数 Parameter	符号 Symbols	D2S B05	D2S B10	D2S B20	D2S B40	D2S B60	D2S B80	单位 Unit
最大可重复峰值反向电压 Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	V
最大均方根电压 Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	V
最大直流阻断电压 Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	V
最大正向平均整流电流 Maximum average forward rectified current	$I_{F(AV)}$	1.5						A
正向不重复浪涌电流 8.3 ms单一正弦半波 Non-repetitive peak forward surge current 8.3 ms singlehalf sine-wave	I_{FSM}	80						A
熔断系数 $t \leq 8.3$ ms Current squared time $t \leq 8.3$ ms	I^2t	32						A ² S
最大正向电压 @ $I_F=0.75A$ Maximum forward voltage	V_F	1.05						V
最大反向电流 @ V_{DC} TA= 25°C Maximum reverse current	I_R	5						μA
典型热阻 Typical thermal resistance (Note 1)	$R_{\theta JL}$	10						°C/W
工作结温和存储温度 Operating junction and storage temperature range	T_j, T_{STG}	-55 --- +150						°C

备注 Note:

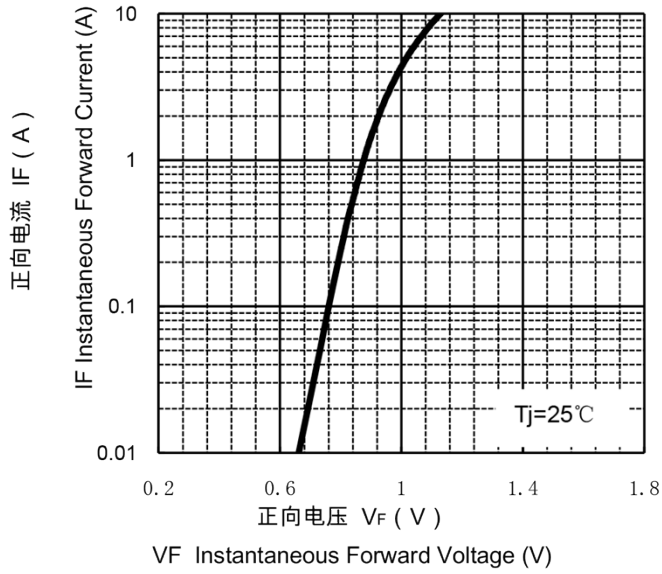
1) 安装在PCB板上, 从PN结到引脚的热阻。

1) Thermal resistance from junction to lead, PCB mounted.

特性曲线 Characteristic Curves

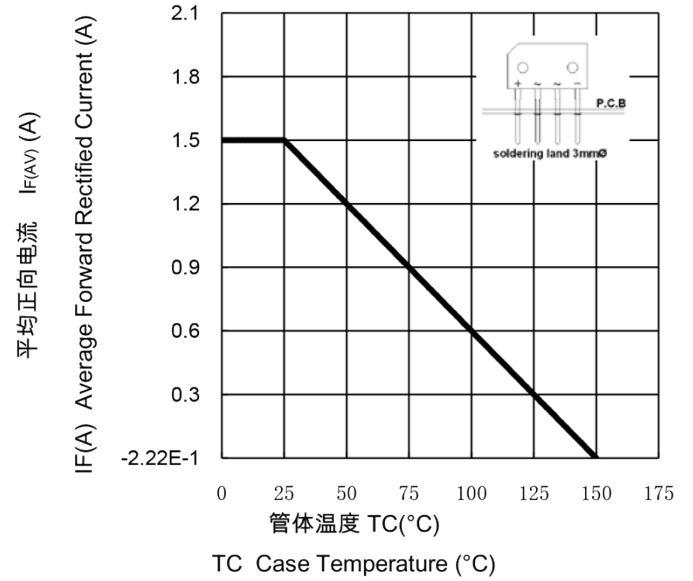
正向特性曲线 (典型值)

TYPICAL FORWARD CHARACTERISTIC



正向电流降额曲线

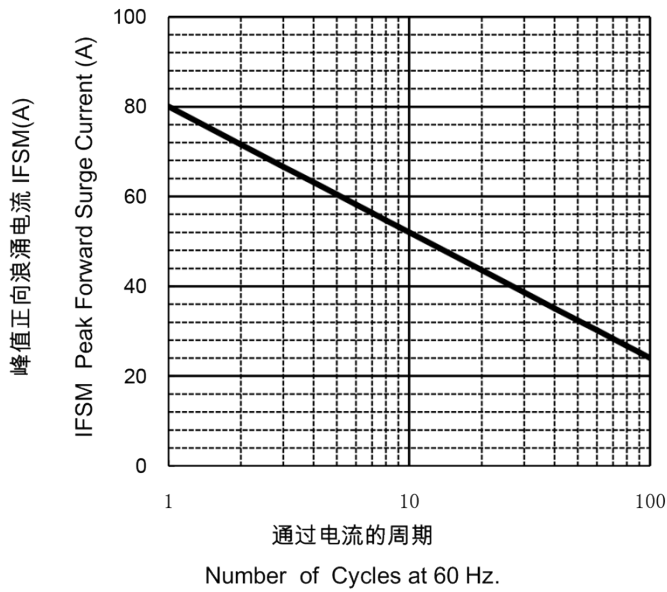
FORWARD CURRENT DERATING CURVE



浪涌特性曲线 (最大值)

MAXIMUM NON REPETITIVE

PEAK FORWARD SURGE CURRENT



反向特性曲线

Typical Reverse Characteristics

